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January 2015

FPF2290 Over-Voltage Protection Load Switch

Features

- Surge Protection
 - IEC 61000-4-5: ±100 V
- Selectable Over-Voltage Protection (OVP) with OV1 and OV2 Logic inputs
 - 5.9 V ±100 mV
 - 10 V ±100 mV
 - 14 V ±280 mV
 - 23 V ±460 mV
- Over-Temperature Protection (OTP)
- Ultra-Low On-Resistance: Typ. 33 mΩ
- ESD Protection
 - Human Body Model (HBM): > 2 kV
 - Charged Device Model (CDM): > 1 kV
 - IEC 61000-4-2 Air Discharge: > 15 kV

Applications

- Mobile Handsets and Tablets
- Portable Media Players
- MP3 Players

Description

The FPF2290 features a low- R_{ON} internal FET and an operating voltage range of 2.5 V to 23 V. An internal clamping circuit is capable of shunting surge voltages of ± 100 V, protecting downstream components and enhancing system robustness. The FPF2290 features over-voltage protection that powers down the internal FET if the input voltage exceeds the OVP threshold. The OVP threshold is selectable via Logic select pins (OV1 and OV2). Over-temperature protection also powers down the device at 130° C (typical).

The FPF2290 is available in a fully "green" compliant 1.3 mm × 1.8 mm Wafer-Level Chip-Scale Package (WLCSP) with backside laminate.

Related Resources

http://www.fairchildsemi.com/

Ordering Information

Part Number	Operating Temperature Range	Top Mark	Package	Packing Method
FPF2290BUCX_F130	-40°C – +85°C	HR	12-Ball, 0.4 mm Pitch WLCSP	Tape & Reel

Block Diagram

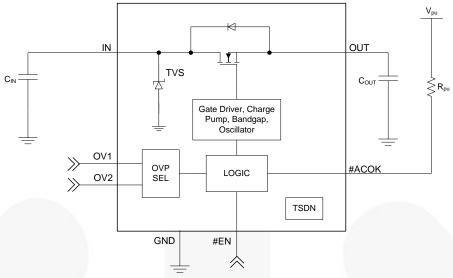


Figure 1. Functional Block Diagram

Note:

1. Setting OV1 and OV2 logic level are recommended before IN is applied.

Pin Configuration

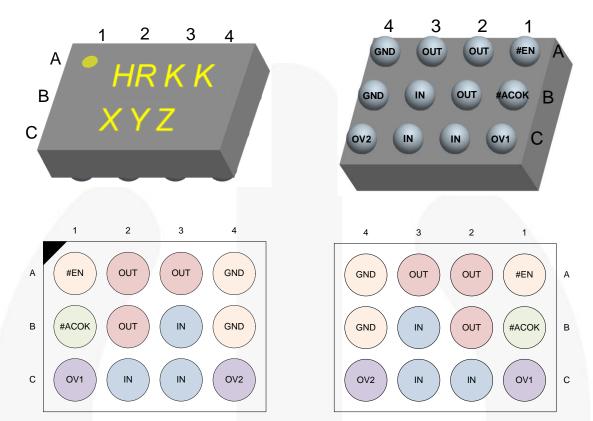


Figure 2. Pin Configuration (Top View)

Figure 3. Pin Configuration (Bottom View)

Pin Definitions

Name	Bump	Туре	Description				
IN	B3, C2, C3	Input/Supply	Switch Input and Device Supply				
OUT	A2, A3, B2	Output	Switch Output to Load				
#ACOK	B1	Output	Power Good (Open-Drain Output)		Hi-Z: V _{IN} < V _{IN_MIN} OR V _{IN} > V _{OVLO}		
#ACOK B1	ы	1 Output			LOW: Voltage Stable		
#EN	A1	Input	Device Enable (Active LOW)				
OV1/2	C1, C4	Input	OVLO Selection Input (see Table 1)				
OV 1/2	01, 04	Input	Note: Appy OV1 and OV2 Logic levels before VIN is applied.				
GND	A4, B4	Supply	Device Ground				

Table 1. OVLO Selection

OV1	OV2	OVP Trip Level
LOW	LOW	5.9 V ±100 mV
HIGH	LOW	10 V ±100 mV
LOW	HIGH	14 V ±280 mV
HIGH	HIGH	23 V ±460 mV

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter			Max.	Unit
V _{IN}	V_IN to GND & V_IN to V_OUT = GND or Float	-0.3	29.0	V	
V _{OUT}	V_OUT to GND		-0.3	V _{IN} + 0.3	V
V _{OVn}	OV1 and OV2 to GND		-0.3	6.0	V
V _{EN_ACOK}	Maximum DC Voltage Allowed on #EN or #ACOK Pin			6	V
I _{IN}	Switch I/O Current (Continuous)			4.5	Α
t _{PD}	Total Power Dissipation at T _A = 25°C		1.48	W	
T _{STG}	Storage Temperature Range	-65	+150	°C	
TJ	Maximum Junction Temperature			+150	°C
TL	Lead Temperature (Soldering, 10 Seconds)		+260	°C	
Θ_{JA}	Thermal Resistance, Junction-to-Ambient ⁽²⁾ (1-in. ² Pad of 2-		84.1	°C/W	
	IFC 64000 4.2 System Level FSD	Air Discharge	15		
FCD	IEC 61000-4-2 System Level ESD	Contact Discharge	8	10	kV
ESD	Human Body Model, ANSI/ESDA/JEDEC JS-001-2012 All Pins				KV
	Charged Device Model, JESD22-C101 All Pins				
Surge	IEC 61000-4-5, Surge Protection	V _{IN}	±100		V

Note:

2. Measured using 2S2P JEDEC std. PCB.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Min.	Max.	Unit
V _{IN}	Supply Voltage	2.5	23.0	V
T _A	Operating Temperature	-40	+85	°C

Electrical Characteristics

 T_A = -40°C to 85°C, V_{IN} = 2.5 to 23 V, unless otherwise indicated. Typical values are V_{IN} = 5.0 V, I_{IN} ≤ 3 A, C_{IN} = 0.1 μF and T_A = 25°C.

Symbol	Parameter	Conditions		Min.	Тур.	Max.	Unit
Basic Opera	tion	1		•	•		
V _{IN_CLAMP}	Input Clamping Voltage	I _{IN} = 10 mA			35		V
ΙQ	Input Quiescent Current	V _{IN} = 5 V, #EN = 0 V			80	115	μΑ
I _{IN_Q}	OVLO Supply Current	OV1 = LOW, OV2 = LOW V _{IN} = 6.5 V, V _{OUT} = 0 V			63	90	μA
		V _{IN} Rising	0 1 - LOV,	5.80	5.90	6.00	
		V _{IN} Falling		5.75			
		V _{IN} Rising	OV1 = HIGH,	9.90	10.00	10.10	
	O V 16 T: 1	V _{IN} Falling	OV2 = LOW	9.85			,,
V_{IN_OVLO}	Over-Voltage Trip Level	V _{IN} Rising	OV1 = LOW,	13.72	14.0	14.28	V
		V _{IN} Falling	OV2 = HIGH	13.52			
	7	V _{IN} Rising	OV1 = HIGH,	22.54	23.0	23.46	
		V _{IN} Falling	OV2 = HIGH	22.34			
Ron	Resistance from V _{IN} to V _{OUT}	V _{IN} = 5 V, I _O	V _{IN} = 5 V, I _{OUT} = 1 A, T _A = 25°C		33	40	mΩ
Соит	OUT Load Capacitance ⁽³⁾	V _{IN} = 5 V		0.1		1000.0	μF
T _{SDN}	Thermal Shutdown ⁽³⁾				130		°C
T _{SDN_HYS}	Thermal Shutdown Hysteresis ⁽³⁾				20		°C
Digital Signa	als	1				l	
V _{OL}	#ACOK Output Low Voltage	I _{SINK} = 1 mA				0.4	V
I _{ACOK}	#ACOK Leakage Current	V _{I/O} = 3.0 V, #ACOK Deasserted				0.5	μΑ
V _{IH}	Input HIGH Voltage (#EN, OVx)	V _{IN} = 2.5 V to V _{OVLO}		1.2			V
V _{IL}	Input LOW Voltage (#EN, OVx)	$V_{IN} = 2.5 \text{ V to } V_{OVLO}$. /		0.5	V
I _{IN}	Input Leakage Current (#EN, OVx)	V _{IN} = 5.0 V, V _{OUT} = Float				1.0	μA
Timing Char	acteristics	1		•	•		•
t _{DEB}	Debounce Time	Time from 2.5 V < V_{IN} < V_{IN_OVLO} to V_{OUT} = 0.1 \times V_{IN}		10	15	20	ms
t _{START}	Soft-Start Time	Time from $V_{IN} = V_{IN_min}$ to 0.2×4 #ACOK, $V_{IO} = 1.8 \text{ V}$ with $10 \text{ k}\Omega$ Pull-up Resistor		20	30	40	ms
t _{ON}	Switch Turn-On Time	R_L = 100 Ω , C_L = 22 μ F, V_{OUT} from 0.1 \times V_{IN} to 0.9 \times V_{IN}		1	3	5	ms
t _{OFF}	Switch Turn-Off Time ⁽³⁾	$R_L = 100 \Omega$, $C_L = 0 \mu F$, $V_{IN} > V_{OVLO}$ to $V_{OUT} = 0.8 \times V_{IN}$				150	ns

Note:

3. Guaranteed by characterization and design.



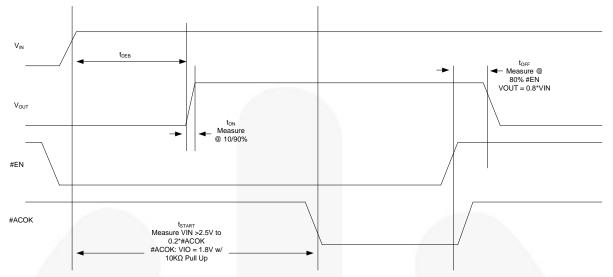


Figure 4. Timing for Power Up and Normal Operation

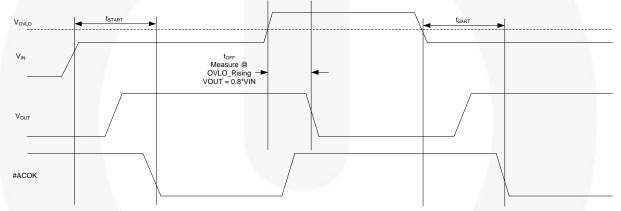
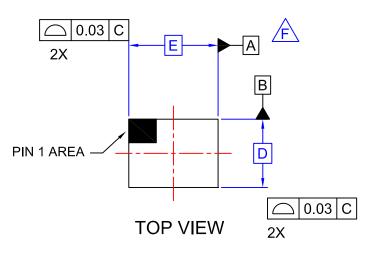
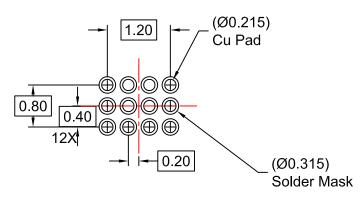


Figure 5. Timing for OVLO Trip

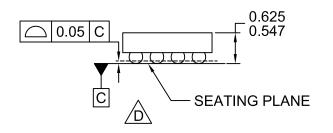
Product-Specific Dimensions

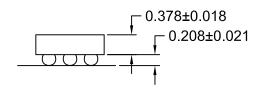
D	E	X	Υ
1288 μm ±30 μm	1828 μm ±30 μm	314 μm ±18 μm	244 μm ±18 μm





RECOMMENDED LAND PATTERN (NSMD PAD TYPE)





SIDE VIEWS

(X)±0.018 ⊕ 0.005(M) C A B ⊕ 0.005(M) C A B Ø0.260±0.02 12X (Y)±0.018

BOTTOM VIEW

NOTES:

- A. NO JEDEC REGISTRATION APPLIES.
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 2009.
- D. DATUM C IS DEFINED BY THE SPHERICAL CROWNS OF THE BALLS.
- E. PACKAGE NOMINAL HEIGHT IS 586 MICRONS ±39 MICRONS (547-625 MICRONS).
- F. FOR DIMENSIONS D, E, X, AND Y SEE PRODUCT DATASHEET.
- G. DRAWING FILENAME: MKT-UC012ZCrev2.
- H. FAIRCHILD SEMICONDUCTOR RECOMMENDS THAT LANDS IN THE LANDPATTERN ARE AT LEAST .215MM DIAMETER AS MEASURED AT THE BOTTOM OF THE LAND, NOT THE TOP EDGE.

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